## NSN 5961-01-023-5127

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View Online at https://aerobasegroup.com/nsn/5961-01-023-5127 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.435 inches **Overall Height:** 0.105 inches **Overall Width:** 0.305 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: